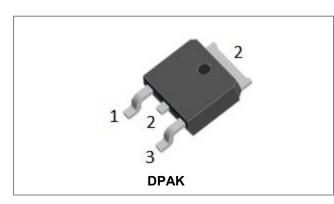


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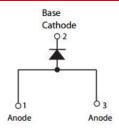
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SDURD1560 ULTRAFAST RECTIFIER



Circuit Diagram



Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Features

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- Terminals finish: 100% Pure Tin
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} Vr	-	600	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=100°C, rectangular wave form	15	А
Peak One Cycle Non-Repetitive Surge Current	IFSM	8.3ms, Half Sine pulse, Tc=25°C	100	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 15A, Pulse, T _J = 25°C	1.53	1.7	V
	VF2	@ 15A, Pulse, T _J = 125°C	1.44	1.5	V
Reverse Current*	I _{R1}	$@V_R = rated V_{R,} T_J = 25^{\circ}C$	0.4	10	μA
	I _{R2}	$@V_R = rated V_{R,} T_J = 125^{\circ}C$	0.3	1	mA
Reverse Recovery Time	t _{rr}	I_F =500mA, I_R =1A,and I_m =250mA	31	50	ns

* Pulse width < 300 μ s, duty cycle < 2%

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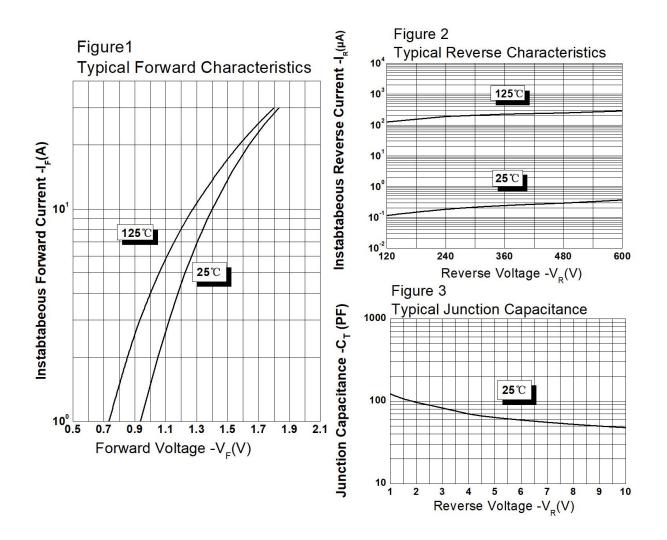


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Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R _{θJC}	DC operation	1.5	°C/W
Approximate Weight	wt	-	0.39	g
Case Style	DPAK			

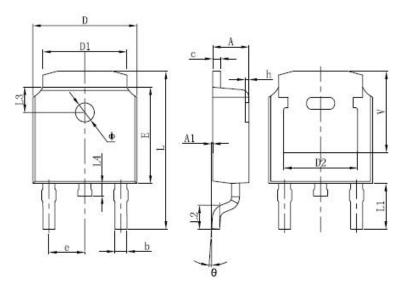
Ratings and Characteristics Curves





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Mechanical Dimensions DPAK



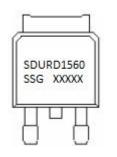
SYMBOL	Dimensions in millimeters			
STWIDUL	Min.	Тур.	Max.	
A	2.18	-	2.39	
A1	-	-	0.13	
b	0.64	-	0.89	
С	0.46	-	0.89	
D	6.35	-	6.73	
D1	4.95	-	5.46	
D2	4.32	-	-	
E	5.97	6.1	6.22	
е	2.29BSC			
L	9.4	-	10.41	
L1	2.90 REF.			
L2	1.4	1.52	1.78	
L3	1.60 REF.			
L4	-	-	1.02	
Φ	1.1	-	1.3	
Θ	0°	-	10°	
V	5.21	-	-	

Ordering Information

Device	Package	Shipping	
SDURD1560	DPAK (Pb-Free)	2500pcs / reel	
SDURD1560TR	DPAK (Pb-Free)	2500pcs / reel	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel Packaging specification.

Marking Diagram



Where XXXXX is YYWWL

SDUR

D 15

60

YΥ

L

WW

SSG

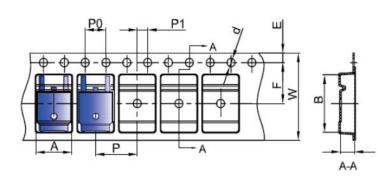
- = Device Type = Package type = Forward Current (15A)
- = Reverse Voltage (600V)
- = SSG

= Year

= Week = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Carrier Tape Specification DPAK



SYMBOL	Millimeters		
STWIDOL	Min.	Max.	
A	6.80	7.00	
В	10.40	10.60	
С	2.60	2.80	
d	Φ1.45	Φ1.65	
E	1.65	1.85	
F	7.40	7.60	
P0	3.90	4.10	
Р	7.90	8.10	
P1	1.90	2.10	
W	15.90	16.30	

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